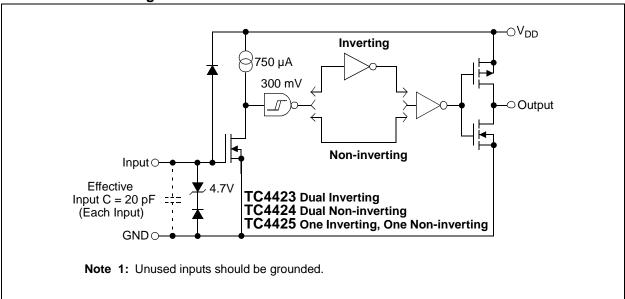
Functional Block Diagram⁽¹⁾



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	+22V
Input Voltage, IN A or IN B	
	$(V_{DD} + 0.3V)$ to $(GND - 5V)$
Package Power Dissipation (T _A	, ≤ 70°C)
DFN	Note 2
PDIP	730 mW
SOIC	470 mW

[†] **Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $T_A = +25^{\circ}C$, with $4.5V \le V_{DD} \le 18V$.									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Input									
Logic '1', High Input Voltage	V _{IH}	2.4	_	_	V				
Logic '0', Low Input Voltage	V_{IL}	_	_	0.8	V				
Input Current	I _{IN}	– 1	_	1	μΑ	$0V \le V_{IN} \le V_{DD}$			
Output									
High Output Voltage	V _{OH}	V _{DD} – 0.025	_	_	V				
Low Output Voltage	V _{OL}	_	_	0.025	V				
Output Resistance, High	R _{OH}	_	2.8	5	Ω	I _{OUT} = 10 mA, V _{DD} = 18V			
Output Resistance, Low	R _{OL}	_	3.5	5	Ω	I _{OUT} = 10 mA, V _{DD} = 18V			
Peak Output Current	I _{PK}	_	3	_	Α				
Latch-Up Protection With- stand Reverse Current	I _{REV}	_	>1.5	_	А	Duty cycle \leq 2%, t \leq 300 µsec.			
Switching Time (Note 1)									
Rise Time	t _R	_	23	35	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF			
Fall Time	t _F	_	25	35	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF			
Delay Time	t _{D1}	_	33	75	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF			
Delay Time	t _{D2}	_	38	75	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF			
Power Supply									
Power Supply Current	I _S	_	1.5 0.15	2.5 0.25	mA	V _{IN} = 3V (Both inputs) V _{IN} = 0V (Both inputs)			

Note 1: Switching times ensured by design.

^{2:} Package power dissipation is dependent on the copper pad area on the PCB.

DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE)

Electrical Specifications: Unless otherwise indicated, operating temperature range with $4.5V \le V_{DD} \le 18V$.										
Parameters	Sym	Min	Тур	Max	Units	Conditions				
Input										
Logic '1', High Input Voltage	V_{IH}	2.4	_	_	V					
Logic '0', Low Input Voltage	V_{IL}	_	_	0.8	V					
Input Current	I _{IN}	-10	_	+10	μΑ	$0V \le V_{IN} \le V_{DD}$				
Output										
High Output Voltage	V _{OH}	V _{DD} – 0.025	_	_	V					
Low Output Voltage	V_{OL}		_	0.025	V					
Output Resistance, High	R _{OH}	_	3.7	8	Ω	I _{OUT} = 10 mA, V _{DD} = 18V				
Output Resistance, Low	R _{OL}	_	4.3	8	Ω	I _{OUT} = 10 mA, V _{DD} = 18V				
Peak Output Current	I _{PK}	_	3.0	_	Α					
Latch-Up Protection Withstand Reverse Current	I _{REV}	_	>1.5	_	Α	Duty cycle ≤2%, t ≤300 µsec				
Switching Time (Note 1)	•									
Rise Time	t _R	_	28	60	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF				
Fall Time	t _F	_	32	60	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF				
Delay Time	t _{D1}	_	32	100	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF				
Delay Time	t _{D2}	_	38	100	ns	Figure 4-1 , Figure 4-2 , C _L = 1800 pF				
Power Supply										
Power Supply Current	I _S	_ _	2.0 0.2	3.5 0.3	mA	V _{IN} = 3V (Both inputs) V _{IN} = 0V (Both inputs)				

Note 1: Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5V \le V_{DD} \le 18V$.										
Parameters	Sym	Min	Тур	Max	Units	Conditions				
Temperature Ranges										
Specified Temperature Range (C)	T _A	0	_	+70	°C					
Specified Temperature Range (E)	T _A	-40	_	+85	°C					
Specified Temperature Range (V)	T _A	-40	_	+125	°C					
Maximum Junction Temperature	TJ	_	_	+150	°C					
Storage Temperature Range	T _A	-65	_	+150	°C					
Package Thermal Resistances										
Thermal Resistance, 8L-6x5 DFN	θ_{JA}	_	33.2	_	°C/W	Typical four-layer board with vias to ground plane				
Thermal Resistance, 8L-PDIP	$\theta_{\sf JA}$	_	125	_	°C/W					
Thermal Resistance, 16L-SOIC	θ_{JA}	_	155	_	°C/W					

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

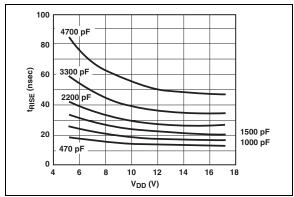


FIGURE 2-1: Rise Time vs. Supply Voltage.

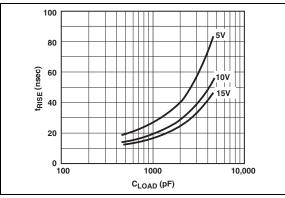


FIGURE 2-2: Rise Time vs. Capacitive Load.

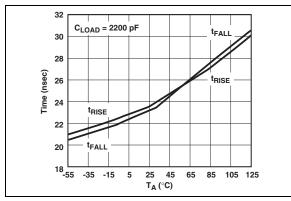


FIGURE 2-3: Rise and Fall Times vs. Temperature.

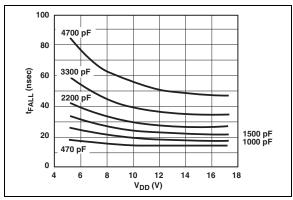


FIGURE 2-4: Fall Time vs. Supply Voltage.

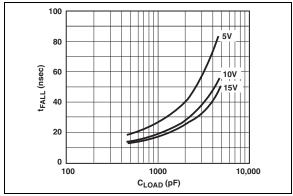


FIGURE 2-5: Fall Time vs. Capacitive Load.

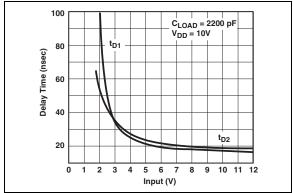


FIGURE 2-6: Propagation Delay vs. Input Amplitude.

Typical Performance Curves (Continued)

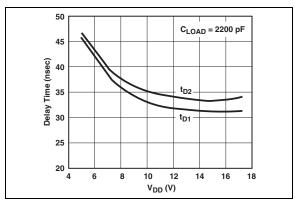


FIGURE 2-7: Propagation Delay Time vs. Supply Voltage.

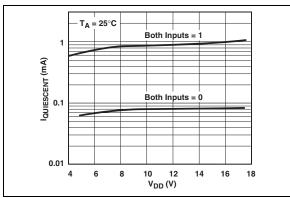


FIGURE 2-8: Quiescent Current vs. Supply Voltage.

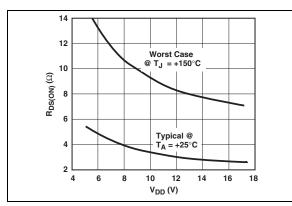


FIGURE 2-9: Output Resistance (Output High) vs. Supply Voltage.

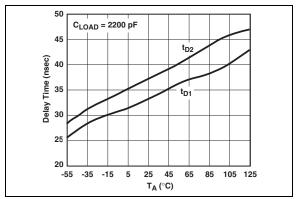


FIGURE 2-10: Propagation Delay Time vs. Temperature.

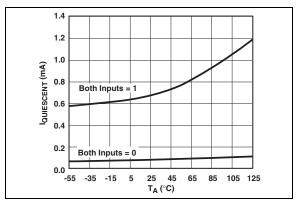


FIGURE 2-11: Quiescent Current vs. Temperature.

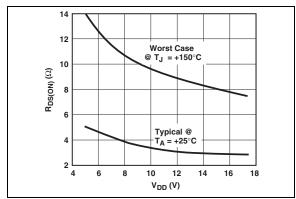


FIGURE 2-12: Output Resistance (Output Low) vs. Supply Voltage.

Typical Performance Curves (Continued)

Note: Load on single output only

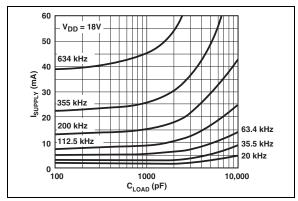


FIGURE 2-13: Capacitive Load.

Supply Current vs.

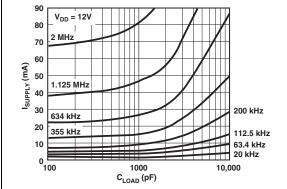


FIGURE 2-14: Supply Current vs. Capacitive Load.

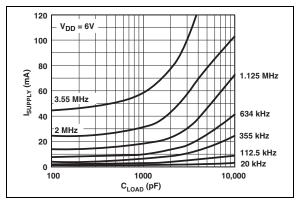


FIGURE 2-15: Capacitive Load.

Supply Current vs.

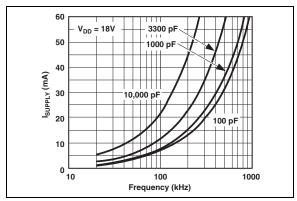


FIGURE 2-16:

Supply Current vs.

Frequency.

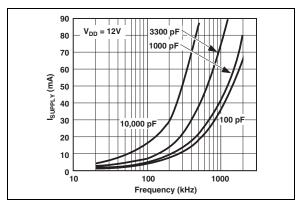


FIGURE 2-17: Frequency.

Supply Current vs.

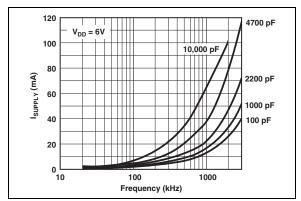


FIGURE 2-18:

Supply Current vs.

Frequency.

Typical Performance Curves (Continued)

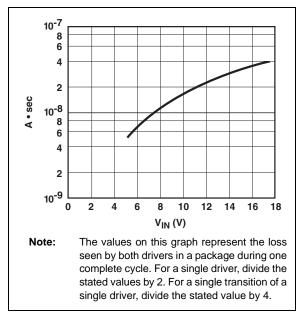


FIGURE 2-19: TC4423 Crossover Energy.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE (1)

8-Pin PDIP	8-Pin DFN	16-Pin SOIC (Wide)	Symbol	Description
1	1	1	NC	No connection
2	2	2	IN A	Input A
_	_	3	NC	No connection
3	3	4	GND	Ground
_	_	5	GND	Ground
_	_	6	NC	No connection
4	4	7	IN B	Input B
_	_	8	NC	No connection
_	_	9	NC	No connection
5	5	10	OUT B	Output B
_	_	11	OUT B	Output B
6	6	12	V_{DD}	Supply input
_	_	13	V_{DD}	Supply input
7	7	14	OUT A	Output A
_	_	15	OUT A	Output A
8	8	16	NC	No connection
_	PAD	_	NC	Exposed Metal Pad

Note 1: Duplicate pins must be connected for proper operation.

3.1 Inputs A and B

Inputs A and B are TTL/CMOS compatible inputs that control outputs A and B, respectively. These inputs have 300 mV of hysteresis between the high and low input levels, allowing them to be driven from slow rising and falling signals, and to provide noise immunity.

3.2 Outputs A and B

Outputs A and B are CMOS push-pull outputs that are capable of sourcing and sinking 3A peaks of current ($V_{DD} = 18V$). The low output impedance ensures the gate of the external MOSFET will stay in the intended state even during large transients. These outputs also have a reverse current latch-up rating of 1.5A.

3.3 Supply Input (V_{DD})

 V_{DD} is the bias supply input for the MOSFET driver and has a voltage range of 4.5V to 18V. This input must be decoupled to ground with a local ceramic capacitor. This bypass capacitor provides a localized low-impedance path for the peak currents that are to be provided to the load.

3.4 Ground (GND)

Ground is the device return pin. The ground pin(s) should have a low-impedance connection to the bias supply source return. High peak currents will flow out the ground pin(s) when the capacitive load is being discharged.

3.5 Exposed Metal Pad

The exposed metal pad of the 6x5 DFN package is not internally connected to any potential. Therefore, this pad can be connected to a ground plane or other copper plane on a printed circuit board to aid in heat removal from the package.

4.0 APPLICATIONS INFORMATION

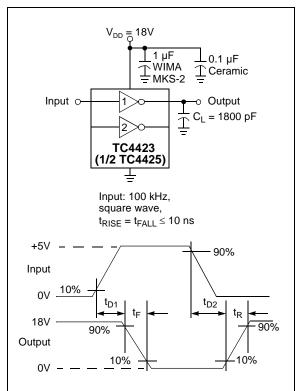


FIGURE 4-1: Inverting Driver Switching Time.

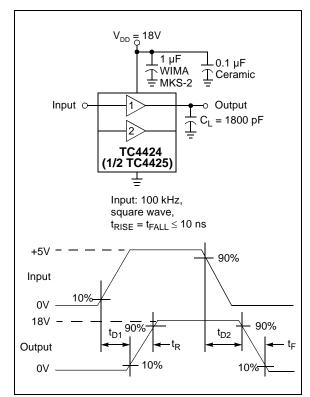


FIGURE 4-2: Non-inverting Driver Switching Time.

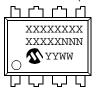
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

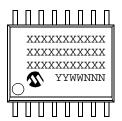
8-Lead DFN



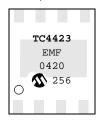
8-Lead PDIP (300 mil)



16-Lead SOIC (300 mil)



Example:







Example:



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

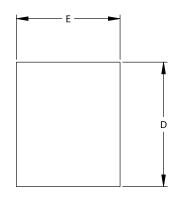
This package is Pb-free. The Pb-free JEDEC designator (e3)

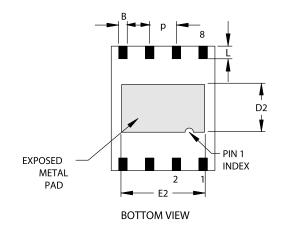
can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

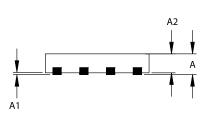
8-Lead Plastic Dual Flat No Lead Package (MF) 6x5 mm Body (DFN-S) - Saw Singulated

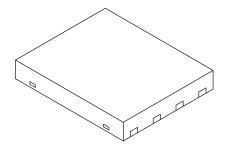
ote: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





TOP VIEW





	Units	INCHES			MILLIMETERS*		
Dimension Limi	ts	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050 BSC			1.27 BSC	
Overall Height	Α	.033	.035	.037	0.85	0.90	0.95
Package Thickness	A2	.031	.035	.037	0.80	0.89	0.95
Standoff	A1	.000	.0004	.002	0.00	0.01	0.05
Base Thickness	A3	.007	.008	.009	0.17	0.20	0.23
Overall Length	E	.195	.197	.199	4.95	5.00	5.05
Exposed Pad Length	E2	.152	.157	.163	3.85	4.00	4.15
Overall Width	D	.234	.236	.238	5.95	6.00	6.05
Exposed Pad Width	D2	.089	.091	.093	2.25	2.30	2.35
Lead Width	В	.014	.016	.019	0.35	0.40	0.47
Lead Length	L	.024		.026	0.60		0.65

Notes:

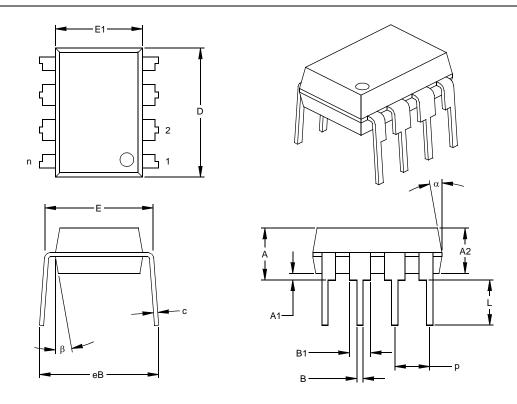
JEDEC equivalent: MO-220

Drawing No. C04-122

Revised 11/3/03

8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		Units	nits INCHES*			MILLIMETERS		
Dimen	sion L	imits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins		n		8			8	
Pitch		р		.100			2.54	
Top to Seating Plane		Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness		A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane		A1	.015			0.38		
Shoulder to Shoulder Width		Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width		E1	.240	.250	.260	6.10	6.35	6.60
Overall Length		D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane		L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness		С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width		B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width		В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§	eВ	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top		α	5	10	15	5	10	15
Mold Draft Angle Bottom		β	5	10	15	5	10	15
* Controlling Parameter					•			

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

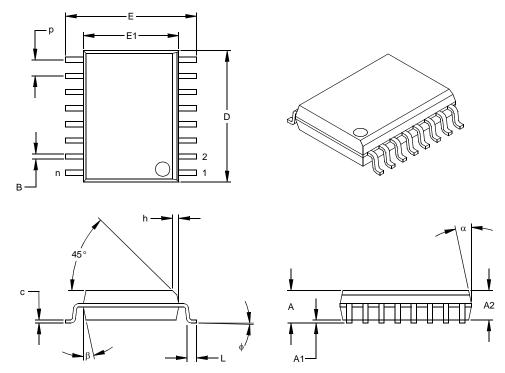
.010" (0.254mm) per side. JEDEC Equivalent: MS-001

Drawing No. C04-018

^{*} Controlling Parameter § Significant Characteristic

16-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	Jnits INCHES*			I.	MILLIMETERS		
Dimension	n Limits	MIN	MIN NOM		MIN	NOM	MAX	
Number of Pins	n		16			16		
Pitch	р		.050			1.27		
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64	
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39	
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30	
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67	
Molded Package Width	E1	.291	.295	.299	7.39	7.49	7.59	
Overall Length	D	.398	.406	.413	10.10	10.30	10.49	
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74	
Foot Length	L	.016	.033	.050	0.41	0.84	1.27	
Foot Angle	ф	0	4	8	0	4	8	
Lead Thickness	С	.009	.011	.013	0.23	0.28	0.33	
Lead Width	В	.014	.017	.020	0.36	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

^{*} Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.

JEDEC Equivalent: MS-013

Drawing No. C04-102

[§] Significant Characteristic

6.0 REVISION HISTORY

Revision E (December 2012)

Added a note to each package outline drawing.



PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X	<u>xx</u>	<u>xxx</u>	¥	Exa	amples:	
Device Tempe Rar	•	Tape & Reel	PB Free	a)	TC4423COE:	3A Dual Inverting MOSFET Driver, 0°C to +70°C, 16LD SOIC package.
Device:	TC4424: 3A Dual M	OSFET Driver, Ir OSFET Driver, N OSFET Driver, C	lon-Inverting	b)	TC4423CPA:	3A Dual Inverting MOSFET Driver, 0°C to +70°C, 8LD PDIP package.
Temperature Range:	C = 0°C to +70° E = -40°C to +8 V = -40°C to +1		C Only)	c)	TC4423VMF:	3A Dual Inverting MOSFET Driver, -40°C to +125°C, 8LD DFN package.
Package:	MF713 = Dual, Flat, I (Tape and I OE = SOIC (Wide OE713 = SOIC (Wide	Reel) e), 16-pin	n Body), 8-lead and Reel)	a)	TC4424COE713:	3A Dual Non-Inverting, MOSFET Driver, 0°C to +70°C, 16LD SOIC package, Tape and Reel.
PB Free:	G = Lead-Free = Blank * Available on selected		ract your local calco	b)	TC4424EPA:	3A Dual Non-Inverting, MOSFET Driver, -40°C to +85°C, 8LD PDIP package.
	representative for ava		act your local sales	a)	TC4425EOE:	3A Dual Complementary, MOSFET Driver, -40°C to +85°C, 16LD SOIC package.
				b)	TC4425CPA:	3A Dual Complementary, MOSFET Driver, 0°C to +70°C, PDIP package.

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

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 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
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